PATENT NUMBER

U.S. UTILITY Patent Application

O.O. OILLITT Catories approach						
haw O.I.P.E.	PATENT DATE					
SCANNED TO Q.A.						

APPLICATION NO. CONT/PRIOR CLASS SUBCLASS ART UNIT **EXAMINER** 09/516615 200 257 2811

Douglas Coolbaugh Gregory Freeman Seshadri Subbanna

Method of fabricating a polysilicon capačitor utilizing fet and bipolar base polysilicon layers

ISSUING CLASSIFICATION							
ORIGINAL	are "	CROSS REFERENCE(S)					
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)				
257	296	257	532				
INTERNATIONAL C	LASSIFICATION						
HO14 27	1108						
HD12 20	3176.94						
HO14 31	1119	,					
HO14 20	100						
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TERMINAL		DRAWINGS	and the same of	CLAIMS ALLOWED			
☐ DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.		
	3	9	1F	7	1		
☐ The term of this patent			NOTICE OF ALLOWANCE MAILED				
subsequent to (date) has been disclaimed.	(Assistant Examiner) (Date)						
The term of this patent shall	and	~1		11-05-02			
not extend beyond the expiration date of U.S Patent. No.				ISSUE FEE			
	′			Amount Due	Date Paid		
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WARNING:							
The information disclosed herein may be res Possession outside the U.S. Patent & Traden	tricted. Unauthorized on nark Office is restricted	disclosure may be p to authorized emplo	prohibited by the to byees and contract	United States Code Title 35 stors only.	i, Sections 122, 181 and 368.		

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